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(54) **DISPLAY PANEL AND LIQUID CRYSTAL DISPLAY INCLUDING THE SAME**

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(57) **ABSTRACT**

(30) **Foreign Application Priority Data**

Dec. 12, 2007 (KR) 10-2007-0129218

The present invention relates to a display panel and a liquid crystal display including the same. The display panel includes a pixel electrode, which includes a first subpixel electrode, a second subpixel electrode, and a third subpixel electrode insulated from each other, a first thin film transistor connected to the first subpixel electrode, a second thin film transistor connected to the second subpixel electrode, a third thin film transistor connected to the third subpixel electrode, a gate line connected to the first, second, and third thin film transistors, a data line connected to the first, second, and third thin film transistors, and a voltage differentiating member to change voltages of the first, second, and third subpixel electrodes, the voltages of the first, second, and third subpixel electrodes being different from each other.

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G02F 1/1343 (2006.01)
G02F 1/136 (2006.01)

(52) **U.S. Cl.** 349/48; 349/38; 349/39; 349/144

(58) **Field of Classification Search** 349/48
See application file for complete search history.

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20 Claims, 13 Drawing Sheets

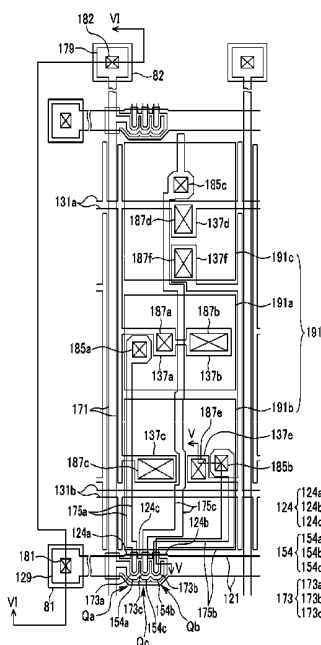


FIG. 1

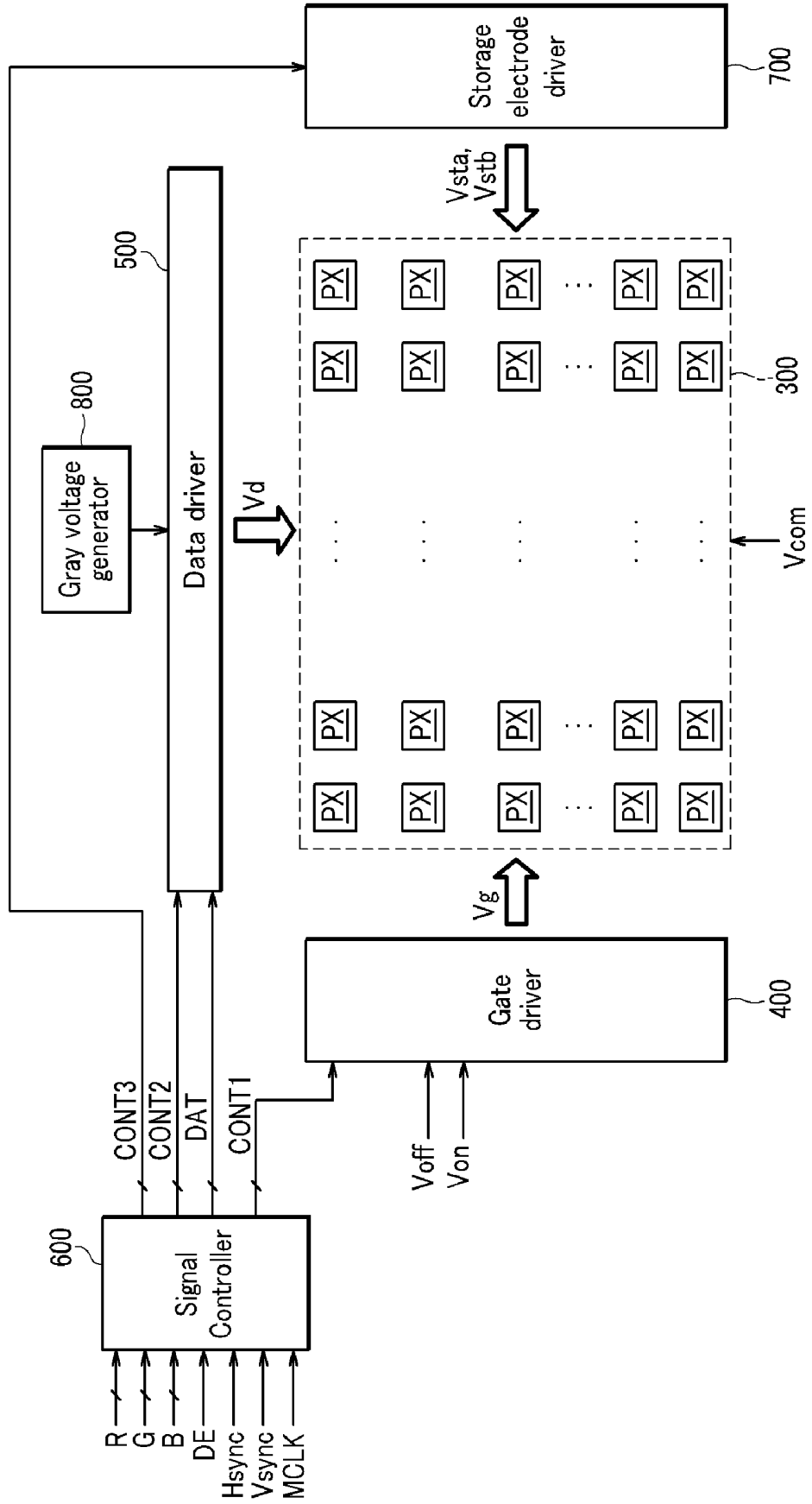


FIG. 2

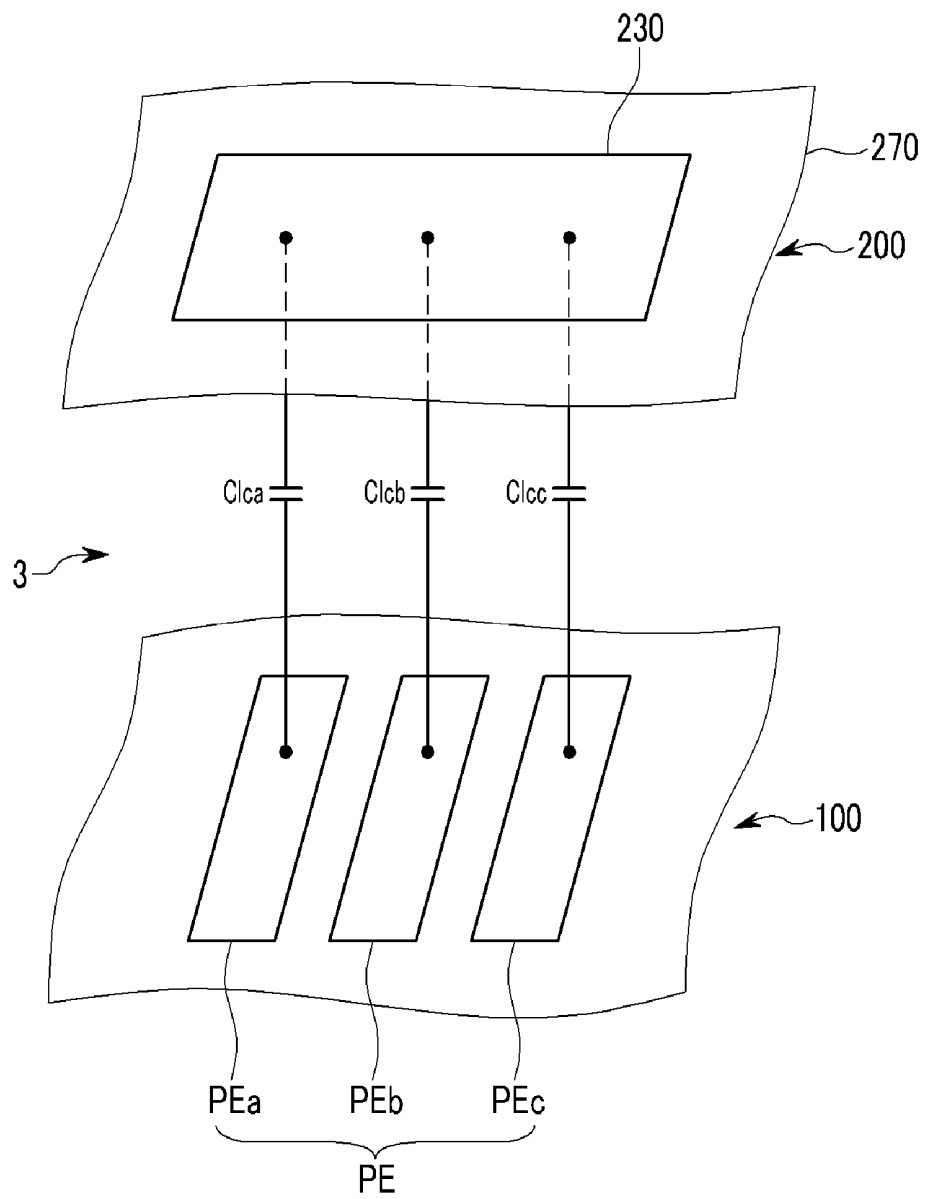


FIG.3

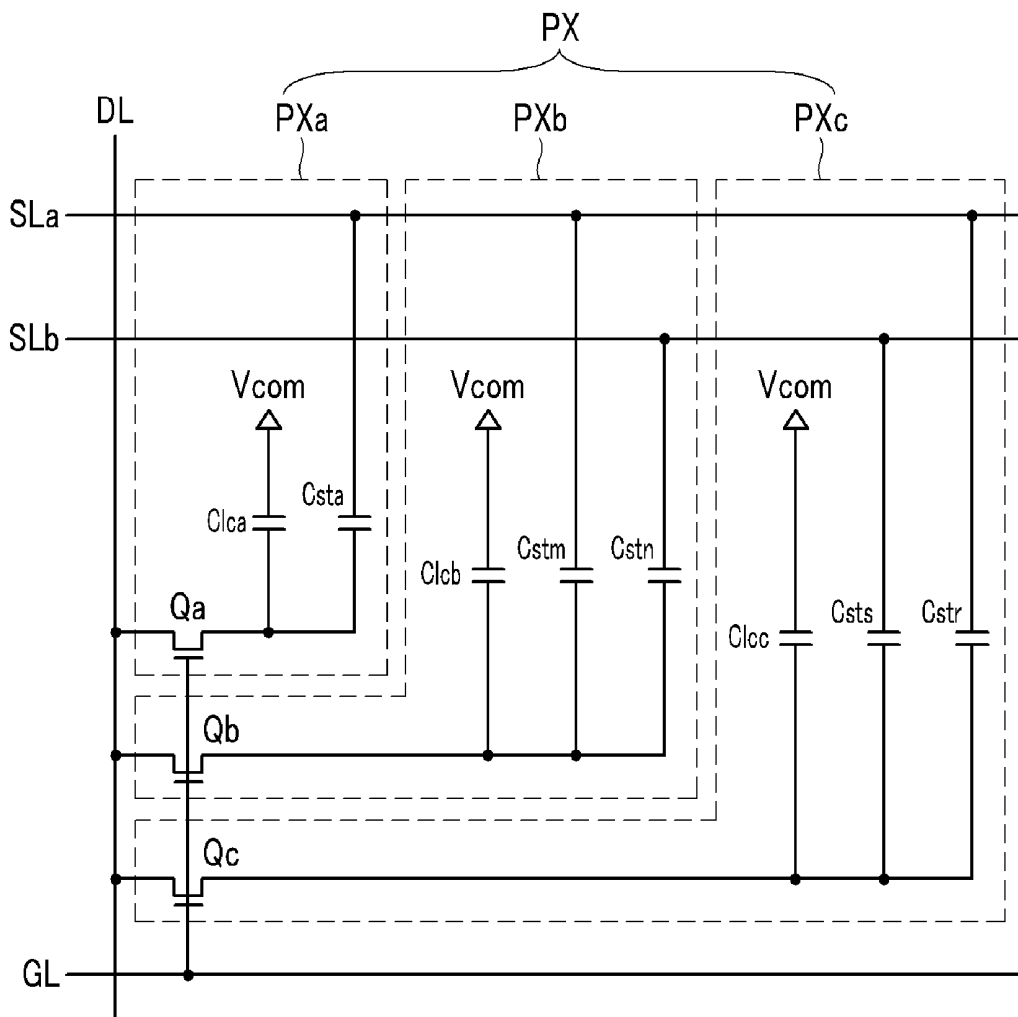


FIG. 4

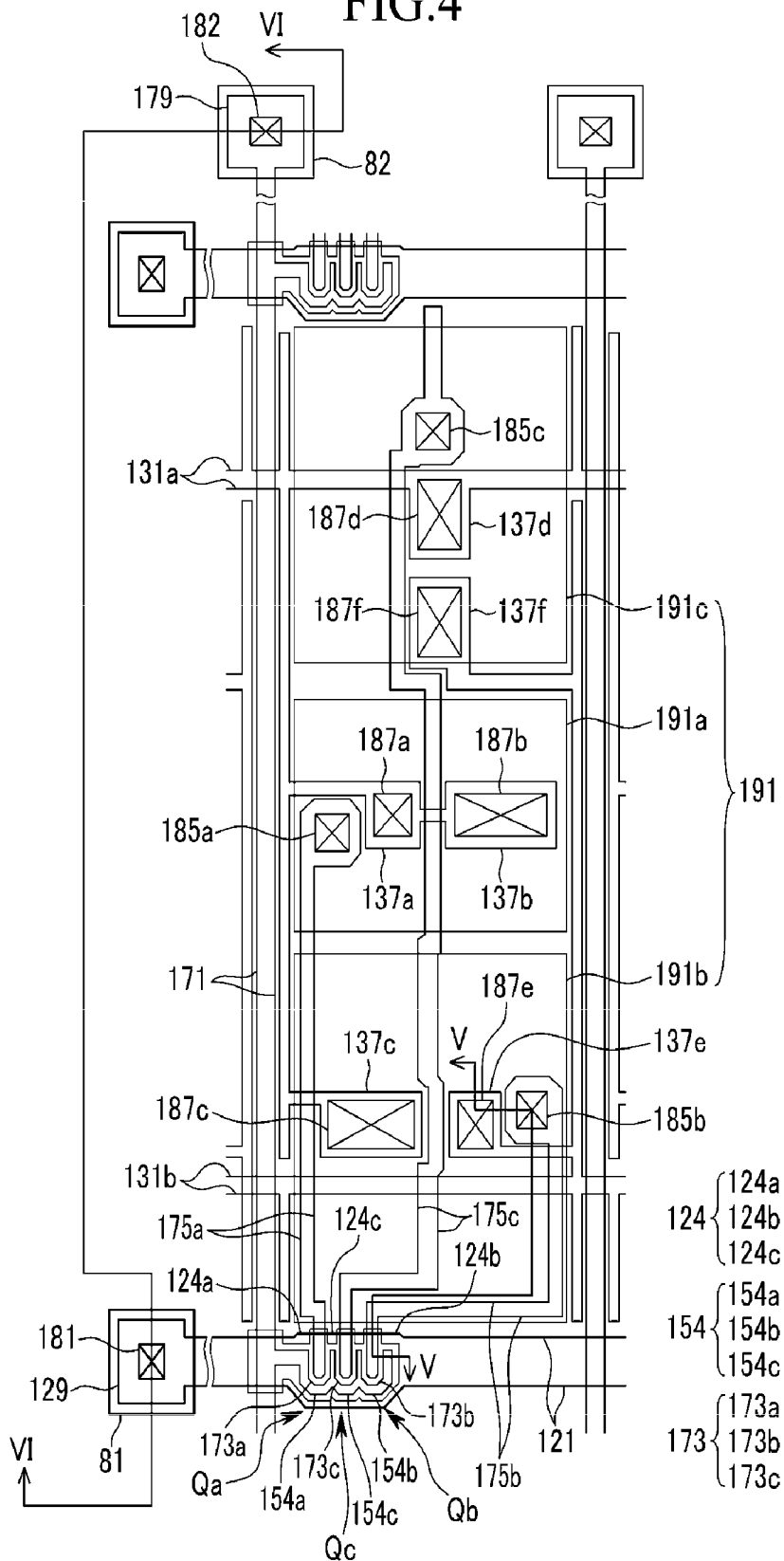


FIG. 5

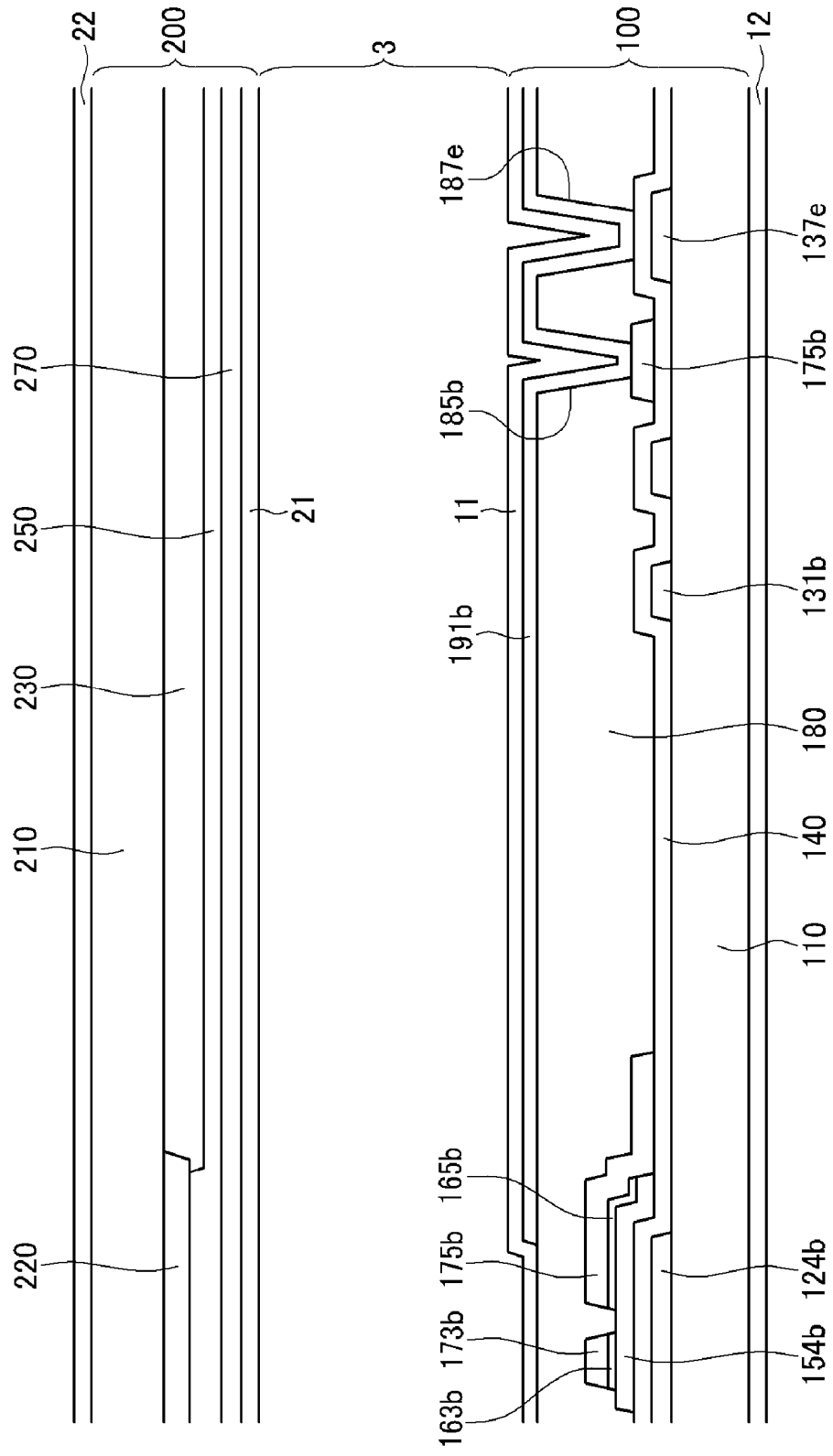


FIG.6

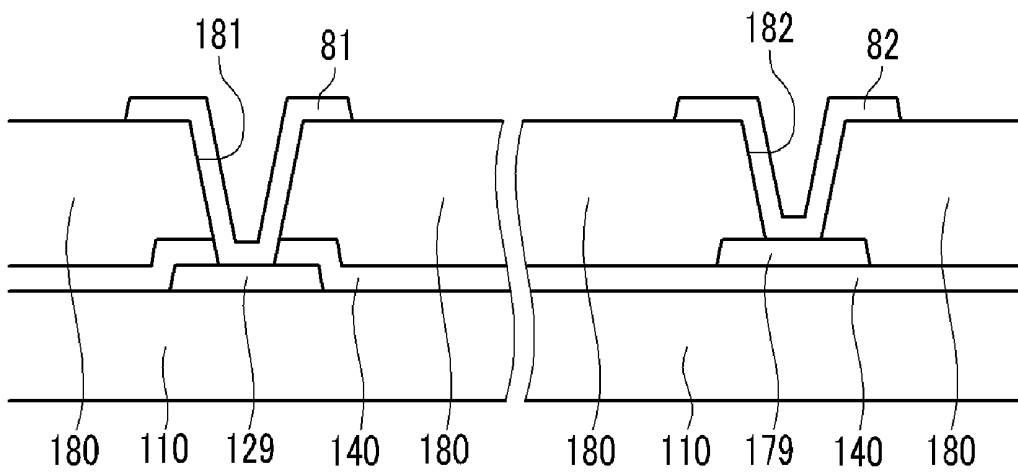


FIG. 7

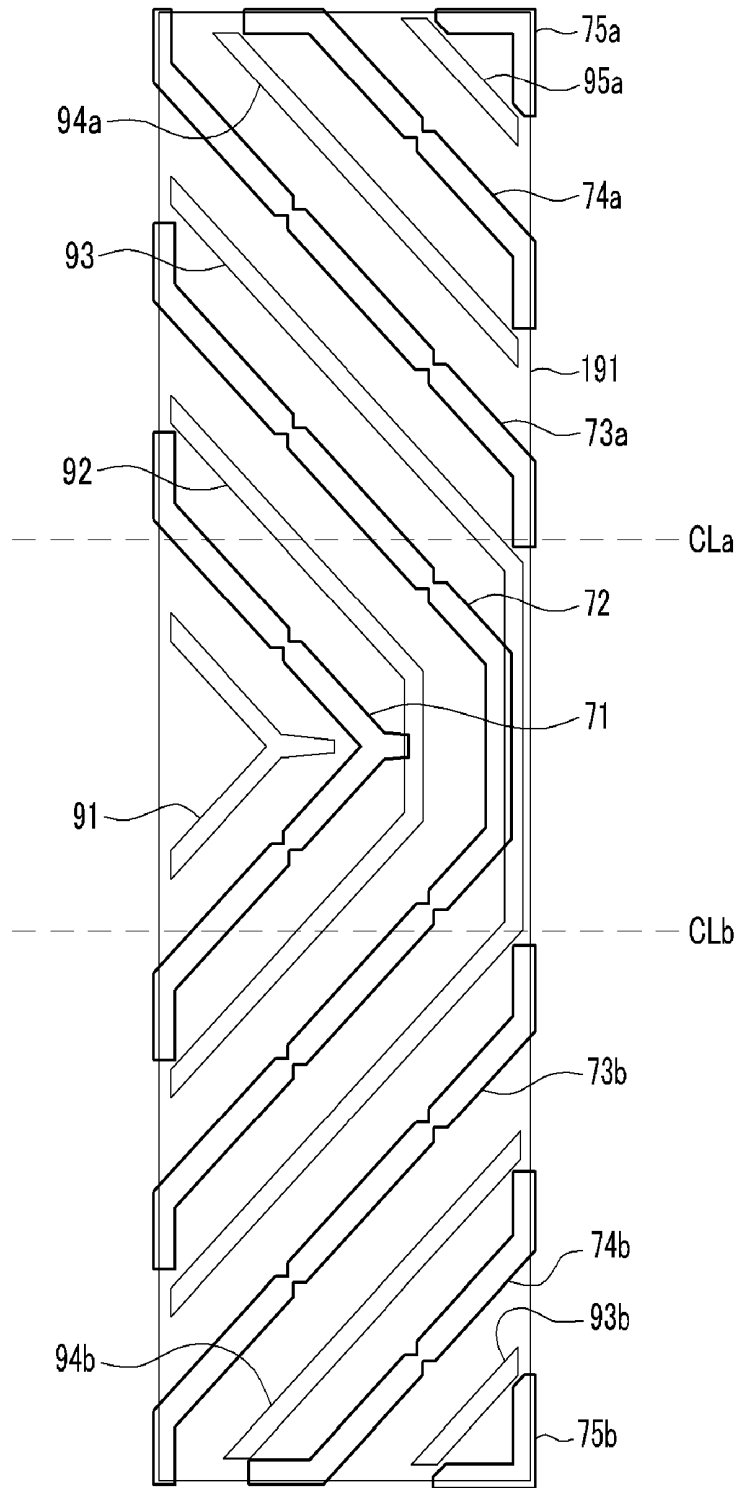


FIG.8

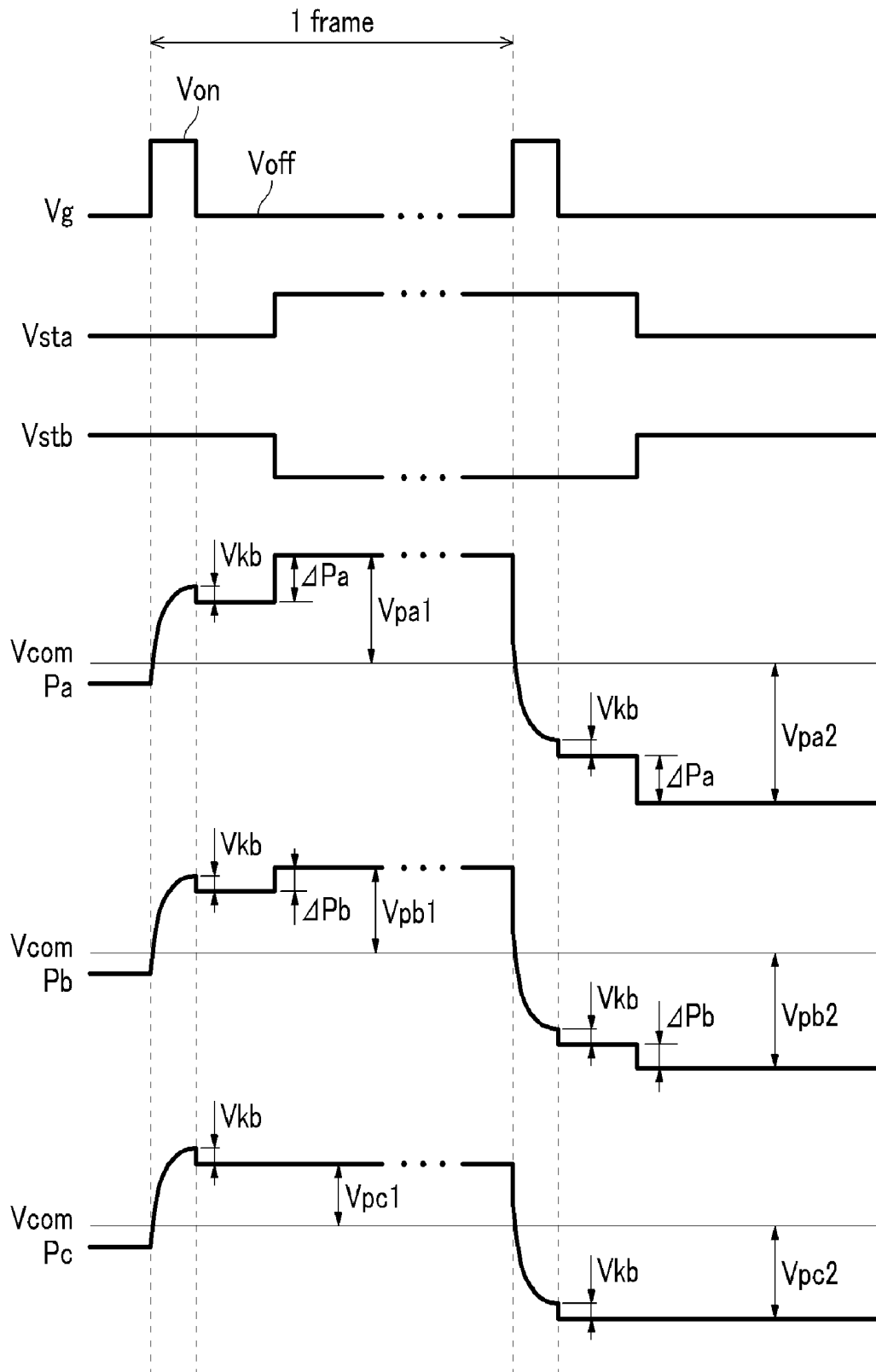


FIG. 9

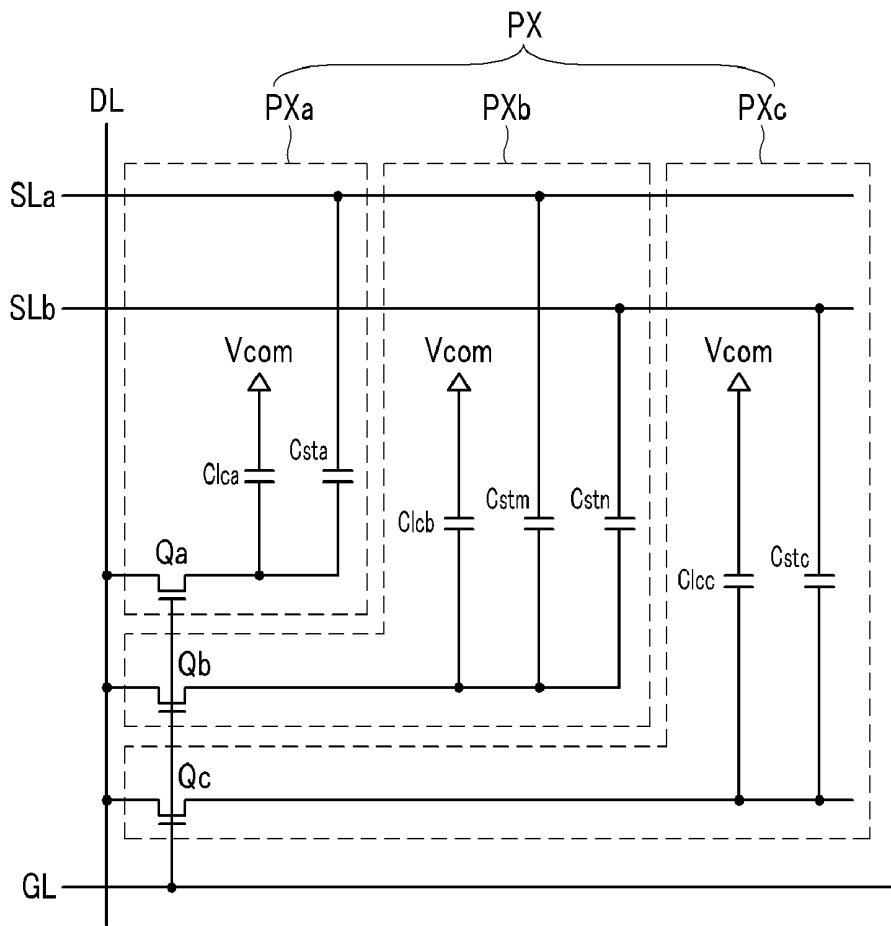


FIG. 10

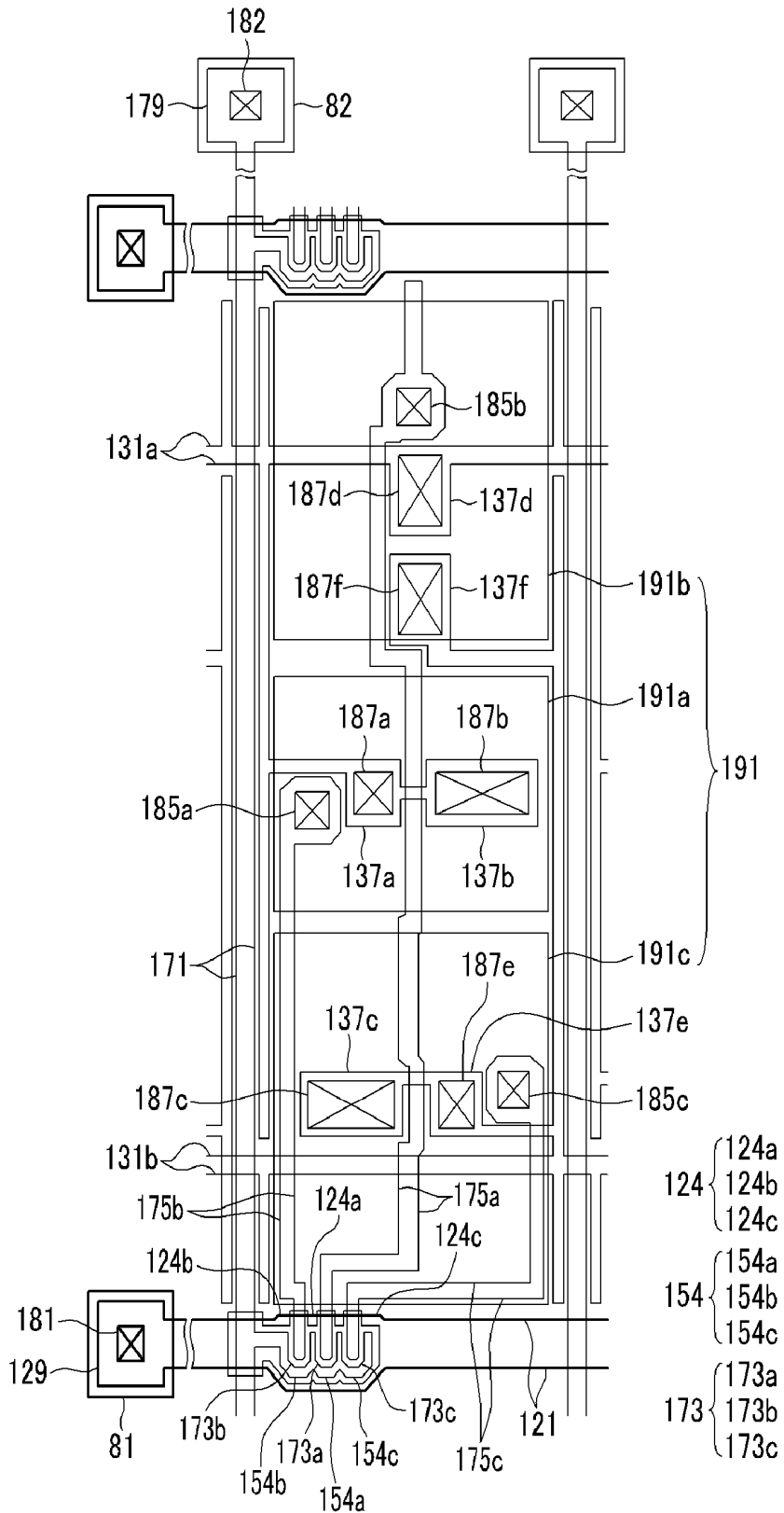


FIG.11

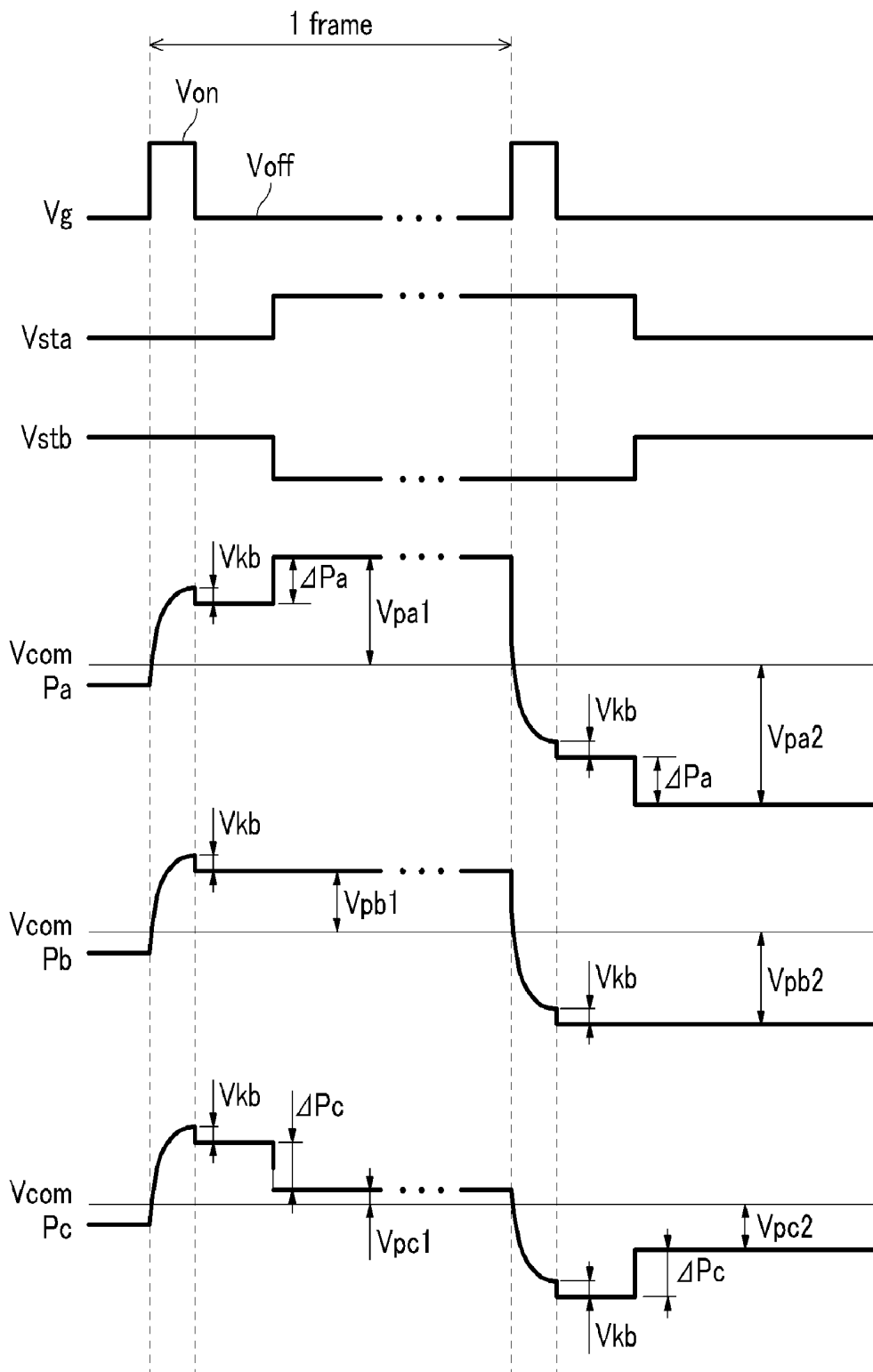


FIG.12A

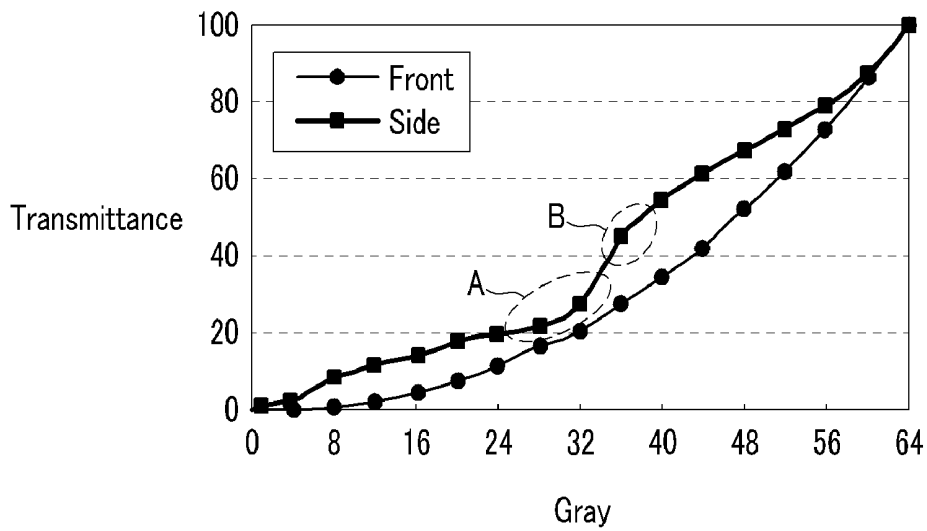


FIG.12B

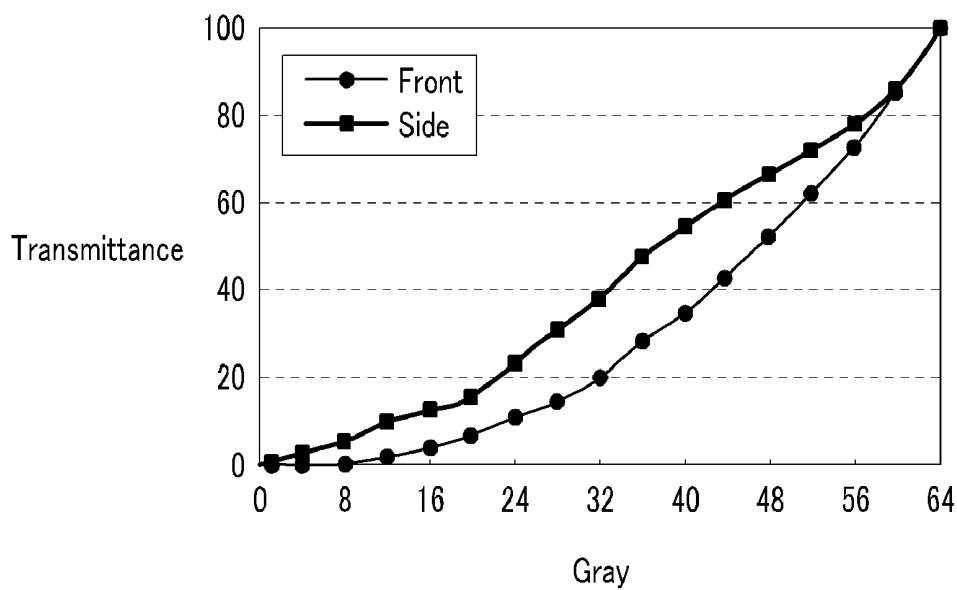


FIG.12C

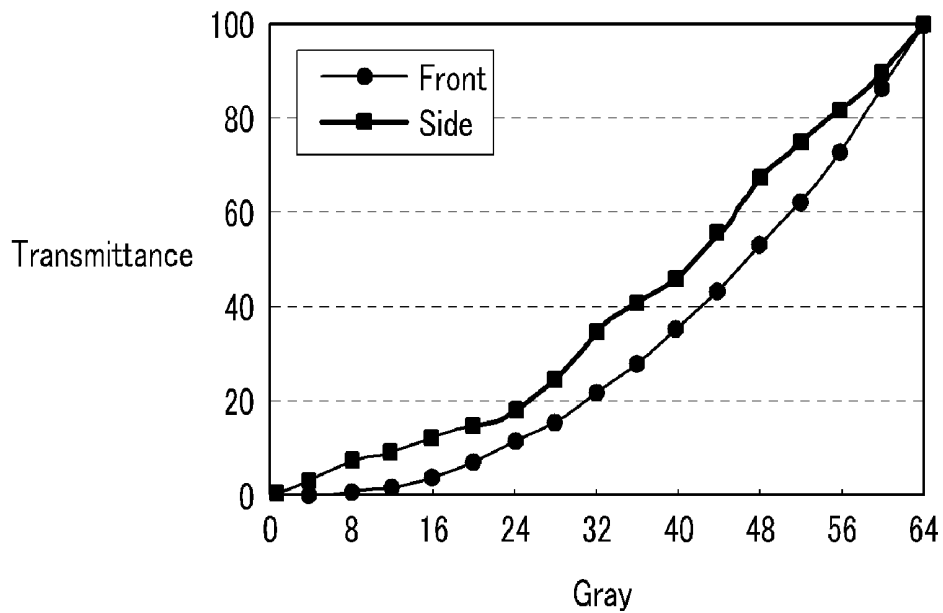
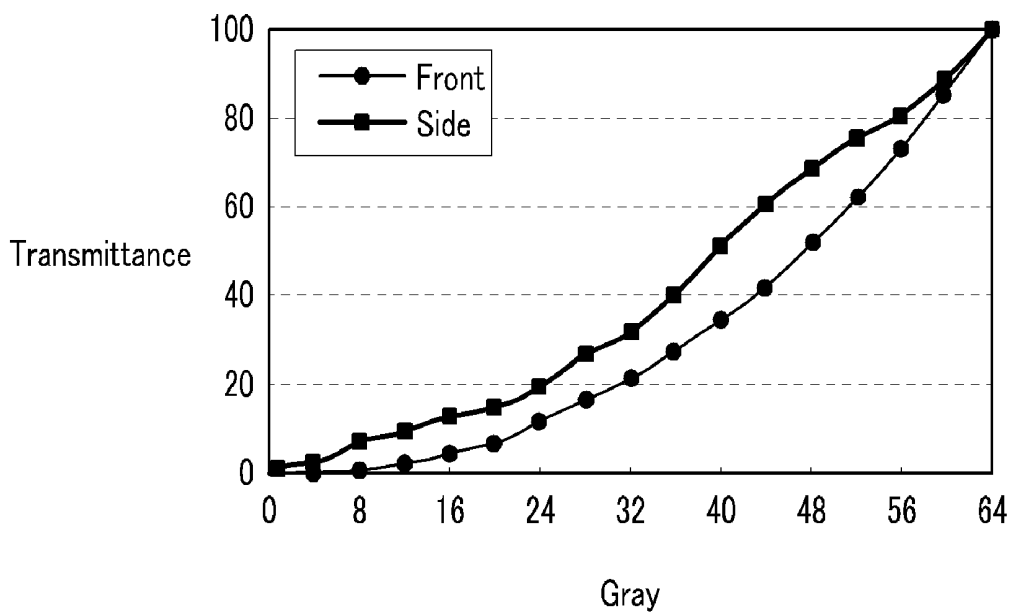


FIG.12D



DISPLAY PANEL AND LIQUID CRYSTAL DISPLAY INCLUDING THE SAME

CROSS-REFERENCE TO RELATED APPLICATION

This application claims priority from and the benefit of Korean Patent Application No. 10-2007-0129218, filed on Dec. 12, 2007, which is hereby incorporated by reference for all purposes as if fully set forth herein.

BACKGROUND OF THE INVENTION

1. Field of the Invention

The present invention relates to a display panel and a liquid crystal display including the same.

2. Discussion of the Background

Liquid crystal displays are one of the most widely used types of flat panel displays. Liquid crystal displays include two panels on which electric field generating electrodes, such as pixel electrodes and a common electrode, are disposed, and a liquid crystal layer disposed between the panels. A voltage is applied to the electric field generating electrodes to generate an electric field in the liquid crystal layer, determine the alignment of liquid crystal molecules of the liquid crystal layer, and control the polarization of input light to display an image.

Liquid crystal displays further include a switching element connected to each pixel electrode, and a plurality of signal lines, such as gate lines or data lines, to apply a voltage to a pixel electrode under the control of the switching element.

Liquid crystal displays include vertical alignment (VA) mode liquid crystal displays and patterned vertically aligned (PVA) mode liquid crystal displays. In VA mode liquid crystal displays, a longitudinal axis of a liquid crystal molecule is perpendicular to upper and lower panels in the absence of an electric field, and thus a contrast ratio is large and a reference viewing angle is wide. The reference viewing angle is defined as a viewing angle making a contrast ratio equal to 1:10 or as a limit angle for the inversion in luminance between grays.

VA mode liquid crystal displays divide one pixel into two subpixels and apply different voltages to the subpixels so that transmittance is changed and side visibility is improved to be close to front visibility.

SUMMARY OF THE INVENTION

The present invention provides a liquid crystal display that may have side visibility that is comparable to the front visibility and may provide natural images when viewed from the side.

Additional features of the invention will be set forth in the description which follows, and in part will be apparent from the description, or may be learned by practice of the invention.

The present invention discloses a display panel including a pixel electrode, which includes a first subpixel electrode, a second subpixel electrode, and a third subpixel electrode that are insulated from each other, a first thin film transistor connected to the first subpixel electrode, a second thin film transistor connected to the second subpixel electrode, a third thin film transistor connected to the third subpixel electrode, a gate line connected to the first, second, and third thin film transistors, a data line connected to the first, second, and third thin film transistors, and a voltage differentiating member to change the voltages of the first, second, and third subpixel electrodes to be different from each other.

The present invention also discloses a liquid crystal display including a gate line, a data line crossing the gate line, first and second storage electrode lines, and a pixel connected to the gate line and the data line. The pixel includes a first liquid crystal capacitor including a first subpixel electrode, a second liquid crystal capacitor including a second subpixel electrode, a third liquid crystal capacitor including the third subpixel electrode, a first storage capacitor coupled in parallel to the first liquid crystal capacitor and connected to the first storage electrode line, a second storage capacitor coupled in parallel to the second liquid crystal capacitor and connected to the first and second storage electrode lines, and a third storage capacitor coupled in parallel to the third liquid crystal capacitor and connected to the first and second storage electrode lines. The first and second storage electrode lines receive storage electrode signals with opposite phases from each other, and the charging voltages of the first, second, and third liquid crystal capacitors are different from each other.

The present invention also discloses a liquid crystal display including a gate line, a data line crossing the gate line, first and second storage electrode lines, and a pixel connected to the gate line and the data line. The pixel includes a first liquid crystal capacitor including a first subpixel electrode, a second liquid crystal capacitor including a second subpixel electrode, a third liquid crystal capacitor including a third subpixel electrode, a first storage capacitor coupled in parallel to the first liquid crystal capacitor and connected to the first storage electrode line, a second storage capacitor coupled in parallel to the second liquid crystal capacitor and connected to the first and second storage electrode lines, and a third storage capacitor coupled in parallel to the third liquid crystal capacitor and connected to the second storage electrode line, wherein the first and second storage electrode lines receive storage electrode signals with opposite phases from each other, and the charging voltages of the first, second, and third liquid crystal capacitors are different from each other.

It is to be understood that both the foregoing general description and the following detailed description are exemplary and explanatory and are intended to provide further explanation of the invention as claimed.

BRIEF DESCRIPTION OF THE DRAWINGS

The accompanying drawings, which are included to provide a further understanding of the invention and are incorporated in and constitute a part of this specification, illustrate embodiments of the invention, and together with the description serve to explain the principles of the invention.

FIG. 1 is a block diagram of a liquid crystal display according to an exemplary embodiment of the present invention.

FIG. 2 is an equivalent circuit diagram of three subpixels of the liquid crystal display according to an exemplary embodiment of the present invention.

FIG. 3 is an equivalent circuit diagram of one pixel of the liquid crystal display according to an exemplary embodiment of the present invention.

FIG. 4 is a layout view of a liquid crystal panel assembly according to an exemplary embodiment of the present invention.

FIG. 5 and FIG. 6 are cross-sectional views of the liquid crystal panel assembly shown in FIG. 4 taken along lines V-V and VI-VI, respectively.

FIG. 7 is a layout view of one example of a pixel electrode applicable to the liquid crystal panel assembly shown in FIG. 4.

FIG. 8 is a waveform diagram showing the driving voltage of the liquid crystal display according to an exemplary embodiment of the present invention.

FIG. 9 is an equivalent circuit diagram of one pixel of a liquid crystal panel assembly according to another exemplary embodiment of the present invention.

FIG. 10 is a layout view of the liquid crystal panel assembly according to another exemplary embodiment of the present invention.

FIG. 11 is a waveform diagram showing the driving voltage of the liquid crystal display according to another exemplary embodiment of the present invention.

FIG. 12A is a graph showing gamma curves of the front and the side of the liquid crystal display according to the conventional art.

FIG. 12B, FIG. 12C, and FIG. 12D are graphs showing gamma curves of the front and the side of the liquid crystal display according to various exemplary embodiments of the present invention.

DETAILED DESCRIPTION OF THE ILLUSTRATED EMBODIMENTS

The invention is described more fully hereinafter with reference to the accompanying drawings, in which embodiments of the invention are shown. This invention may, however, be embodied in many different forms and should not be construed as limited to the embodiments set forth herein. Rather, these embodiments are provided so that this disclosure is thorough, and will fully convey the scope of the invention to those skilled in the art. In the drawings, the size and relative sizes of layers and regions may be exaggerated for clarity. Like reference numerals in the drawings denote like elements.

It will be understood that when an element or layer is referred to as being "on" or "connected to" another element or layer, it can be directly on or directly connected to the other element or layer, or intervening elements or layers may be present. In contrast, when an element is referred to as being "directly on" or "directly connected to" another element or layer, there are no intervening elements or layers present.

A liquid crystal display according to an exemplary embodiment of the present invention will be described in detail below with reference to the drawings.

FIG. 1 is a block diagram of a liquid crystal display according to an exemplary embodiment of the present invention, FIG. 2 is an equivalent circuit diagram of three subpixels of the liquid crystal display according to an exemplary embodiment of the present invention, and FIG. 3 is an equivalent circuit diagram of one pixel of the liquid crystal display according to an exemplary embodiment of the present invention.

As shown in FIG. 1, a liquid crystal display according to an exemplary embodiment of the present invention includes a liquid crystal panel assembly 300, a gate driver 400, a data driver 500, a storage electrode driver 700, a gray voltage generator 800, and a signal controller 600.

As viewed in an equivalent circuit, the liquid crystal panel assembly 300 includes a plurality of signal lines GL, DL, SLa, and SLb, and a plurality of pixels PX connected to the signal lines GL, DL, SLa, and SLb and disposed in a matrix form. In a structure shown in FIG. 2, the liquid crystal panel assembly 300 includes lower and upper panels 100 and 200 that face each other, and a liquid crystal layer 3 that is disposed between the panels 100 and 200.

The signal lines include a plurality of gate lines GL to transmit gate signals (also referred to as "scanning signals"),

a plurality of data lines DL to transmit data signals, and a plurality of pairs of first and second storage electrode lines SLa and SLb, as shown in FIG. 3, to transmit storage electrode signals Vsta and Vstb, respectively. The first and the second storage electrode lines SLa and SLb are respectively applied with the first and the second storage electrode signals Vsta and Vstb having opposite phases from each other. The gate lines GL and the first and second storage electrode lines SLa and SLb extend in a row direction to be parallel to each other, and the data lines DL extend in a column direction to be parallel to each other.

The liquid crystal panel assembly according to the present exemplary embodiment includes a plurality of signal lines GL, DL, SLa, and SLb and a plurality of pixels PX connected thereto.

Each pixel PX includes three subpixels, that is, first, second, and third subpixels PXa, PXb, and PXc, and the first, second, and third subpixels PXa, PXb, and PXc include first, second, and third switching elements Qa, Qb, and Qc and the first, second, and third liquid crystal capacitors Clca, Clcb, and Clcc.

The first, second, and third switching elements Qa, Qb, and Qc are each a three terminal element, such as a thin film transistor, provided on the lower panel 100, a control terminal thereof is connected to the gate line GL, an input terminal thereof is connected to the data line DL, and an output terminal thereof is connected to the liquid crystal capacitors Clca, Clcb, and Clcc and the storage capacitors Csta, Cstb (i.e., Cstm and Cstn), and Cstc (i.e., Cstr and Csts).

The liquid crystal capacitors Clca, Clcb, and Clcc are connected to the switching elements Qa, Qb, and Qc and have two terminals of subpixel electrodes PEa, PEb, and PEc of the lower panel 100 and a common electrode 270 of the upper panel 200. The liquid crystal layer 3 between the subpixel electrodes PEa, PEb, and PEc and the common electrode 270 serves as a dielectric material. The three subpixel electrodes PEa, PEb, and PEc are spaced from each other and make up one pixel electrode PE. The common electrode 270 is disposed on the whole surface of the upper panel 200 and receives the common voltage Vcom. The liquid crystal layer 3 may have negative dielectric anisotropy. The liquid crystal molecules of the liquid crystal layer 3 are arranged such that a longitudinal axis of the liquid crystal molecules is perpendicular to the surfaces of the two panels in the absence of an electric field.

The first subpixel PXa further includes a first storage capacitor Csta connected to the first switching element Qa and a first storage electrode line SLa, and the first storage capacitor Csta is formed by overlapping the first storage electrode line SLa of the lower panel 100 and the first subpixel electrode PEa with an insulator therebetween.

The second subpixel PXb includes second and third storage capacitors Cstm and Cstn. The second storage capacitor Cstm is connected to the second switching element Qb and the first storage electrode line SLa, and is formed by overlapping the first storage electrode line SLa and the second subpixel electrode PEb with an insulator therebetween. The third storage capacitor Cstn is connected to the second switching element Qb and the second storage electrode line SLb, and is formed by overlapping the second storage electrode line SLb and the second subpixel electrode PEb with an insulator therebetween.

The third subpixel PXc includes fourth and fifth storage capacitors Cstr and Csts. The fourth storage capacitor Cstr is formed by overlapping the first storage electrode line SLa and the third subpixel electrode PEc with an insulator therebetween, and the fifth storage capacitor Csts is formed by over-

lapping the second storage electrode line SLb and the third subpixel electrode PEc with an insulator therebetween.

The capacitance of the second storage capacitor Cstm is less than that of the third storage capacitor Cstn. Also, the capacitance of the fourth storage capacitor Cstr is the same as the capacitance of the fifth storage capacitor Csts. Here, the capacitances may be determined by the distances between the subpixel electrodes PXa, PXb, and PXc and the first or second storage electrode line SLa or SLb, the overlapping areas, and the dielectric ratio of the insulator. The dielectric ratio of the insulator is uniform such that the distances between the subpixel electrodes PXa, PXb, and PXc and the first or second storage electrode line SLa or SLb and the overlapping areas are mainly controlled to control the capacitances of the second, third, fourth, and fifth storage capacitors Cstm, Cstn, Cstr, and Csts.

In order to display a color in the liquid crystal display, each pixel may essentially represent any one of the primary colors (spatial division), or may represent any one of the primary colors in turn (temporal division) according to a passage of time, such that the desired color is recognized by a spatial or temporal sum of the primary colors. The primary colors may be, for example, three primary colors such as a red color, a green color, and a blue color. FIG. 2 shows an example of the spatial division in which each pixel PX includes a color filter 230 representing one of the primary colors in an area of the upper panel 200 facing a pixel electrode 191. Alternatively, unlike in FIG. 2, the color filter 230 may be provided on or under the subpixel electrodes PEa, PEb, and PEc on the lower panel 100.

At least one polarizer (not shown) to polarize light is attached on the outer side of the liquid crystal panel assembly 300, and the polarization axis of two polarizers may be crossed. In the case of a reflective liquid crystal display, one of two polarizers 12 and 22 may be omitted. The crossed polarizers block light that is incident into the liquid crystal layer 3 in the absence of an electric field.

Returning again to FIG. 1, the gray voltage generator 800 generates two sets of gray voltages related to transmittance of the pixel PX (or sets of reference gray voltages).

The gate driver 400 is connected to the gate lines GL of the liquid crystal panel assembly 300, and applies the gate signals Vg, which are combinations of a gate-on voltage Von and a gate-off voltage Voff, to the gate lines GL.

The data driver 500 is connected to the data lines DL of the liquid crystal panel assembly 300. The data driver 500 selects the gray voltages from the gray voltage generator 800, and applies the selected gray voltages as data signals to the data lines DL. However, when the gray voltage generator 800 supplies a specific number of reference gray voltages, rather than the voltages for all gray levels, the data driver 500 divides the reference gray voltages so as to generate the gray voltages for all gray levels and selects the data signals from the divided gray voltages.

The storage electrode driver 700 is connected to the first and second storage electrode lines SLa and SLb of the liquid crystal panel assembly 300, and applies a pair of storage electrode signals Vsta and Vstb, which have opposite phases from each other, to the first and second storage electrode lines SLa and SLb, respectively. The storage electrode driver 700 may be provided as one chip along with the gate driver 400.

The signal controller 600 controls the gate driver 400, the data driver 500, the storage electrode driver 700, and the like.

Each driving device 400, 500, 600, 700, and 800 may be directly mounted on the liquid crystal panel assembly 300 in the form of at least one IC chip, or may be mounted on a flexible printed circuit film (not shown) and attached to the

liquid crystal panel assembly 300 in the form of a TCP (tape carrier package). Further, the driving devices 400, 500, 600, 700, and 800 may be mounted on a separate printed circuit board (not shown). Alternatively, the driving devices 400, 500, 600, 700, and 800 may be integrated into the liquid crystal panel assembly 300. Further, the driving devices 400, 500, 600, 700, and 800 may be integrated into a single chip. In this case, at least one driving device 400, 500, 600, 700, and 800 or at least one circuit element of a driving device 400, 500, 600, 700, and 800 may be provided outside the single chip.

Now, the liquid crystal panel assembly according to an exemplary embodiment of the present invention will be described in detail with reference to FIG. 4, FIG. 5, FIG. 6, and FIG. 7.

FIG. 4 is a layout view of a liquid crystal panel assembly according to an exemplary embodiment of the present invention, FIG. 5 and FIG. 6 are cross-sectional views of the liquid crystal panel assembly shown in FIG. 4 taken along lines V-V and VI-VI, respectively, and FIG. 7 is a layout view of one example of a pixel electrode that is applicable to the liquid crystal panel assembly shown in FIG. 4.

Referring to FIG. 4, FIG. 5, and FIG. 6, a liquid crystal display according to an exemplary embodiment of the present invention includes a lower panel 100 and an upper panel 200 facing each other, a liquid crystal layer 3 disposed between two display panels 100 and 200, and a pair of polarizers 12 and 22 attached to the outside surfaces of the display panels 100 and 200, respectively.

Firstly, the lower panel 100 is described.

A plurality of gate lines 121 and a plurality of first and second storage electrode lines 131a and 131b are disposed on an insulation substrate 110.

The gate lines 121 transmit gate signals, and extend in a horizontal direction. Each gate line 121 has a plurality of gate electrode portions 124 that protrude upward and downward, and a wide end 129 for connection with other layers and external driving circuits. Each gate electrode portion 124 includes the first, second, and third gate electrodes 124a, 124b, and 124c.

The first storage electrode line 131a receives a voltage, and includes a stem line almost parallel to the gate lines 121, a plurality of branch lines extended from the stem line, and a plurality of first, second, third, and fourth storage electrodes 137a, 137b, 137c, and 137d. The second storage electrode line 131b is applied with a period voltage having an opposite phase to the voltage applied to the first storage electrode line 131a, and includes a stem line parallel to the gate line 121, a plurality of branch lines extended from the stem line, and a plurality of fifth and sixth storage electrodes 137e and 137f. The first, second, third, fourth, fifth, and sixth storage electrodes 137a, 137b, 137c, 137d, 137e, and 137f are approximately rectangular, and the length of each side is larger than the width of the stem lines and the branch lines. Each storage electrode line 131 is disposed between two neighboring gate lines 121. However, the shape and the arrangement of the storage electrode lines 131 may vary.

A gate insulating layer 140 is disposed on the gate lines 121 and the storage electrode lines 131a and 131b.

A plurality of semiconductor island members 154 is disposed on the gate insulating layer 140. Each semiconductor member 154 includes first, second, and third channel portions 154a, 154b, and 154c disposed on the first, second, and third gate electrodes 124a, 124b, and 124c, respectively.

A pair of first ohmic contact islands (not shown) are disposed on a first channel portion 154a of each semiconductor member 154, a pair of second ohmic contact islands 163b and

165b are disposed on a second channel portion **154b**, and a pair of third ohmic contact islands (not shown) are disposed on a third channel portion **154c**.

A plurality of data lines **171** and a plurality of first, second, and third drain electrodes **175a**, **175b**, and **175c** are disposed on the first, second, and third ohmic contact islands, respectively, and the gate insulating layer **140**.

The data lines **171** transmit data voltages, and substantially extend in a vertical direction to cross the gate lines **121**. Each data line **171** has a plurality of source electrode portions **173** that protrude toward the gate electrode portions **124**, and a wide end **179** for connection with other layers and external driving circuits. Each source electrode portion **173** has a "U" shape, and includes a plurality of first, second, and third source electrodes **173a**, **173b**, and **173c** connected to each other.

The first, second, and third drain electrodes **175a**, **175b**, and **175c** are spaced apart from each other and are spaced apart from the data lines **171**. The first, second, and third drain electrodes **175a**, **175b**, and **175c** face the first, second, and third source electrodes **173a**, **173b**, and **173c** with respect to the first, second, and third gate electrodes **124a**, **124b**, and **124c**.

Each drain electrode **175a**, **175b**, and **175c** includes one end portion with a wide area and another end portion with a bar shape, and the bar end portions are respectively enclosed by the source electrodes **173a**, **173b**, and **173c**.

The first, second, and third gate electrodes **124a**, **124b**, and **124c**, the first, second, and third source electrodes **173a**, **173b**, and **173c**, and the first, second, and third drain electrodes **175a**, **175b**, and **175c** make up the first, second, and third thin film transistors (TFT) **Qa**, **Qb**, and **Qc** as well as the first, second, and third channel portions **154a**, **154b**, and **154c**, and the channels of the first, second, and third thin film transistors **Qa**, **Qb**, and **Qc** are disposed in the first, second, and third channel portions **154a**, **154b**, and **154c** between the first, second, and third source electrodes **173a**, **173b**, and **173c** and the first, second, and third drain electrodes **175a**, **175b**, and **175c**.

A passivation layer **180** is disposed on the data lines **171**, the drain electrodes **175a**, **175b**, and **175c**, and the exposed semiconductor members **154**.

The passivation layer **180** has a plurality of contact holes **182**, **185a**, **185b**, and **185c** respectively exposing the wide end portions **179** of the data lines **171** and the first, second, and third drain electrodes **175a**, **175b**, and **175c**. The passivation layer **180** and the gate insulating layer **140** have a plurality of contact holes **181** respectively exposing the wide end portions **129** of the gate lines **121**. Also, the passivation layer **180** has first, second, third, fourth, fifth, and sixth openings **187a**, **187b**, **187c**, **187d**, **187e**, and **187f** disposed on the first, second, third, fourth, fifth, and sixth storage electrodes **137a**, **137b**, **137c**, **137d**, **137e**, and **137f**, respectively.

A plurality of pixel electrodes **191** and a plurality of contact assistants **81** and **82** are disposed on the passivation layer **180**.

Each pixel electrode **191** includes first, second, and third subpixel electrodes **191a**, **191b**, and **191c**. Each subpixel electrode **191a**, **191b**, and **191c** is approximately rectangular and they are arranged in a vertical direction. However, the shape and the arrangement thereof may vary.

The area of the first subpixel electrode **191a** may be in the range of 10% to 50% of the entire area of the pixel electrode **191**, the area of the second subpixel electrode **191b** may be in the range of 20% to 50% of the entire area of the pixel electrode **191**, and the area of the third subpixel electrode **191c** may be in the range of 40% to 70% of the entire area of the pixel electrode **191**.

The first subpixel electrode **191a** is connected to the first drain electrode **175a** through the contact hole **185a**, the second subpixel electrode **191b** is connected to the second drain electrode **175b** through the contact hole **185b**, and the third subpixel electrode **191c** is connected to the third drain electrode **175c** through the contact hole **185c**. That is, the first, second, and third subpixel electrodes **191a**, **191b**, and **191c** are spaced from each other.

The first, second, and third subpixel electrodes **191a**, **191b**, and **191c** and the common electrode **270** of the upper panel **200** form the first, second, and third liquid crystal capacitors **C1ca**, **C1cb**, and **C1cc** along with the liquid crystal layer **3** therebetween such that they maintain the applied voltages after the thin film transistors **Qa**, **Qb**, and **Qc** are turned off.

The first subpixel electrode **191a** overlaps the first storage electrode line **131a** including the first and second storage electrodes **137a** and **137b**. Here, the passivation layer **180** has the first and second openings **187a** and **187b** on the portions where the first subpixel electrode **191a** and the first and second storage electrodes **137a** and **137b** overlap each other such that the gate insulating layer **140** only exists between the pixel electrode **191** and the first and second storage electrodes **137a** and **137b** in the corresponding portions, and the distance between the pixel electrode **191** and the first and second storage electrodes **137a** and **137b** may be decreased to increase the capacitance of the storage capacitor **Csta** formed by the first subpixel electrode **191a** and the first and second storage electrodes **137a** and **137b**.

The second subpixel electrode **191b** overlaps the first storage electrode line **131a** including the third storage electrode **137c** and the second storage electrode line **131b** including the fifth storage electrode **137e**. Here, the overlapping area between the second subpixel electrode **191b** and the first storage electrode line **131a** is greater than the overlapping area between the second subpixel electrode **191b** and the second storage electrode line **131b**. The passivation layer **180** has the third and fifth openings **187c** and **187e** disposed on the overlapping area between the second subpixel electrode **191b** and the third and fifth storage electrodes **137c** and **137e** such that only the gate insulating layer **140** remains between the pixel electrode **191** and the third and fifth storage electrodes **137c** and **137e** in the corresponding portion. The capacitance of the storage capacitor **Cstm** formed by the first storage electrode line **131a** and the second subpixel electrode **191b** may be larger than that of the storage capacitor **Cstn** of the second storage electrode line **131b** and the second subpixel electrode **191b** in consideration of the overlapping area and the area of the openings **187c** and **187e**.

The third subpixel electrode **191c** overlaps with the first storage electrode line **131a**, which includes the fourth storage electrode **137d**, and the second storage electrode line **131b**, which includes the sixth storage electrode **137f**. Here, the overlapping area between the third subpixel electrode **191c** and the first storage electrode line **131a** is substantially the same as the overlapping area between the third subpixel electrode **191c** and the second storage electrode line **131b**. Also, the passivation layer **180** includes the fourth and sixth openings **187d** and **187f** in the overlapping area between the third subpixel electrode **191c** and the fourth and sixth storage electrodes **137d** and **137f**, such that only the gate insulating layer **140** remains between the third subpixel electrode **191c** and the fourth and sixth storage electrodes **137d** and **137f** in the corresponding portion. The capacitance of the storage capacitor **Cstr** formed by the first storage electrode line **131a** and the third subpixel electrode **191c** is determined to be the same as that of the storage capacitor **Csts** formed by the second stor-

age electrode line **131b** and the third subpixel electrode **191c** in consideration of the overlapping area and the area of the openings **187c** and **187e**.

The first and second storage electrode lines **131a** and **131b** overlap the pixel electrode **191**, and include a plurality of branch lines parallel to the data lines **171**.

On the other hand, the first drain electrode **175** extends to cross the central portion of the pixel electrode **191** in the vertical direction. The first opening **187a** and the first contact hole **185a** are on an opposite side of the second drain electrode **175b** than the second opening **187b**, and the third opening **187c** is on an opposite side of the second drain electrode **175b** than the fifth opening **187e** and the fifth contact hole **185e**. The fourth opening **187d**, the sixth opening **187f**, and the third contact hole **185c** are disposed in a line with the second drain electrode **175b**.

On the other hand, as shown in FIG. 7, the pixel electrode **191** may include a plurality of cutouts **91**, **92**, **93**, **94a**, **94b**, **95a**, and **95b**. Here, the pixel electrode **191** may include the cut lines CLa and CLb indicated in FIG. 7, which divide it into the first, second, and third subpixel electrodes **191a**, **191b**, and **191c**.

The contact assistants **81** and **82** are respectively connected to the end portions **129** and **179** of the gate lines **121** and the data lines **171** through the contact holes **181** and **182**.

The contact assistants **81** and **82** enhance the adhesion between the end portions **129** and **179** of the gate lines **121** and the data lines **171**, and to an external device, and protect them.

Now, the upper panel **200** will be described.

A light blocking member **220** is disposed on an insulation substrate **210** that may be made of transparent glass or plastic. The light blocking member **220** may be referred to as a black matrix, and it blocks light leakage.

A plurality of color filters **230** is disposed on the substrate **210**. The color filters **230** may be mainly disposed in the regions enclosed by the light blocking member **220**, and may extend according to the column of the pixel electrodes **191** in the vertical direction. Each color filter **230** may display one of the primary colors such as red, green, or blue.

An overcoat **250** is disposed on the color filters **230** and the light blocking member **220**.

A common electrode **270** is disposed on the overcoat **250**. As shown in FIG. 7, the common electrode **270** may have a plurality of cutouts **71**, **72**, **73a**, **73b**, **74a**, **74b**, **75a**, and **75b**.

Alignment layers **11** and **21** are disposed at inside surfaces of the display panels **100** and **200**, respectively, and they may be vertical alignment layers.

The liquid crystal layer **3** may have negative dielectric anisotropy. The liquid crystal molecules of the liquid crystal layer **3** are arranged such that a longitudinal axis of the liquid crystal molecules is perpendicular to the surfaces of the two panels **100** and **200** in the absence of an electric field.

Next, the operation of the liquid crystal display will be described in detail with reference to FIG. 8, FIG. 1, FIG. 2, and FIG. 3.

FIG. 8 is a waveform diagram showing the driving voltage of the liquid crystal display according to an exemplary embodiment of the present invention.

Firstly, referring to FIG. 1, the signal controller **600** receives input image signals R, G, and B and input control signals to control display of the input image signals R, G, and B from an external graphics controller (not shown). The input image signals R, G, and B contain luminance information of each pixel PX. The luminance has a specific number of grays, such as 1024 ($=2^{10}$), 256 ($=2^8$), or 64 ($=2^6$). Examples of the input control signals include a vertical synchronization signal

Vsync, a horizontal synchronization signal Hsync, a main clock signal MCLK, and a data enable signal DE.

The signal controller **600** processes the input image signals R, G, and B according to an operating condition of the liquid crystal panel assembly **300** based on the input image signals R, G, and B and the input control signals to generate a gate control signal CONT1, a data control signal CONT2, a storage electrode control signal CONT3, and the like, and thereafter sends the generated gate control signal CONT1 to the gate driver **400**, the generated data control signal CONT2 and the processed image signal DAT to the data driver **500**, and the storage electrode control signal CONT3 to the storage electrode driver **700**. The output image signal DAT is as a digital signal and has the specific number of values (or grays).

The data driver **500** receives digital image signals DAT for a row of pixels PX according to the data control signal CONT2 transmitted from the signal controller **600**, and selects a grayscale voltage corresponding to each digital image signal DAT to convert the digital image signals DAT into analog data signals. Thereafter, the data driver **500** applies the converted analog data signals to corresponding data lines DL.

The gate driver **400** applies a gate-on voltage Von to the gate lines GL according to the gate control signal CONT1 transmitted from the signal controller **600** to turn on the switching elements Qa, Qb, and Qc connected to the gate lines GL. Then, the data voltage Vd applied to the data lines DL is applied to corresponding the subpixels PX1, PX2, and PX3 through the turned-on switching elements Qa, Qb, and Qc.

Here, the first, second, and third subpixel electrodes **191a**, **191b**, and **191c** that make up one pixel electrode **191** are respectively connected to the switching elements Qa, Qb, and Qc, but the switching elements Qa, Qb, and Qc are all connected to the same gate line GL and the data line DL. Accordingly, the first, second, and third subpixel electrodes **191a**, **191b**, and **191c** receive the same data voltage Vd through the same data line DL at the same time.

Accordingly, as shown in FIG. 8, each subpixel electrode voltage Pa, Pb, and Pc is increased to almost the same level. Next, if the switching elements Qa, Qb, and Qc are turned-off, the first, second, and third subpixel electrodes **191a**, **191b**, and **191c** are floated. Here, the gate voltage Vg changes from the gate-on voltage Von to the gate-off voltage Voff such that each of the subpixel electrode voltages Pa, Pb, and Pc are decreased by a kick-back voltage Vkb.

Thereafter, the voltages of the first and second storage electrode lines SLa and SLb are changed such that the voltages of the first, second, and third subpixel electrodes **191a**, **191b**, and **191c** change and become different from each other.

In detail, the first subpixel electrode voltage Pa is increased by the value ΔPa according to the change of the first storage electrode signal Vsta.

The second subpixel electrode voltage Pb is increased by the value ΔPb , which is somewhat offset, rather than the variation of the first storage electrode signal Vsta.

The influences of the first storage electrode signal Vsta and the second storage electrode signal Vstb are offset from each other such that the third subpixel electrode voltage Pc is maintained.

Accordingly, in relation to the common voltage Vcom, the voltage of first subpixel electrode **191a** becomes Vpa1, the voltage of the second subpixel electrode **191b** becomes Vpb1, the voltage of the third subpixel electrode **191c** becomes Vpc1, and the order of the magnitude thereof is $Vpa1 > Vpb1 > Vpc1$.

These subpixel electrode voltages V_{pa1} , V_{pb1} , and V_{pc1} are maintained during one frame.

In this way, if the potential difference is generated between both terminals of the first, second, and third liquid crystal capacitors $Clca$, $Clcb$, and $Clcc$, a primary electric field that is perpendicular to the surfaces of the display panels **100** and **200** is generated in the liquid crystal layer **3**. Hereafter, the pixel electrode **191** and the common electrode **270** are referred to as "field generating electrodes". The liquid crystal molecules of the liquid crystal layer **3** are arranged in response to the electric field such the long axis thereof are vertically declined in the direction of the electric field, and the change degree of the polarization of the light that is incident to the liquid crystal layer **3** is changed according to the declination degree of the liquid crystal molecules. This change of the polarization appears as a change of the transmittance of the polarizer, thereby displaying images of the liquid crystal display.

The declination angle of the liquid crystal molecules is changed according to the intensity of the electric field, and because the voltages of the three liquid crystal capacitors $Clca$, $Clcb$, and $Clcb$ are different, the declination angles of the liquid crystal molecules of the three liquid crystal capacitors $Clca$, $Clcb$, and $Clcb$ are different such that the luminance of the three subpixels are different. Accordingly, if the voltages of the three liquid crystal capacitors $Clca$, $Clcb$, and $Clcb$ are appropriately controlled, the images shown at the side of the display may approximate the image shown in the front, that is to say, the gamma curve of the side may be approximately close to the gamma curve of the front to thereby improve the side visibility.

By repeating this procedure every horizontal period (also referred to as a "1H" period and equal to one period of the horizontal synchronization signal Hsync and the data enable signal DE), the data voltages V_d are applied to all pixels PX to display images for a frame.

When the next frame starts after one frame finishes, the inversion control signal RVS applied to the data driver **500** is controlled such that the polarity of the data signals is reversed (which is referred to as "frame inversion").

That is to say, referring to FIG. **8**, the polarity of the voltage applied to each subpixel electrode is reversed in the next frame, and the procedure of the previous frame is repeated, the voltage of the first subpixel electrode **191a** becomes V_{pa2} , the voltage of the second subpixel electrode **191b** becomes V_{pb2} , the voltage of the third subpixel electrode **191c** becomes V_{pc2} , and the order of the magnitude thereof is $V_{pa2} > V_{pb2} > V_{pc2}$.

On the other hand, the inversion control signal RVS may also be controlled such that the polarity of the data signals flowing in a data line are periodically reversed during one frame (for example row inversion and dot inversion), or the polarity of the data signals in one packet is reversed (for example column inversion and dot inversion).

Now, a liquid crystal panel assembly according to another exemplary embodiment of the present invention will be described in detail with reference to FIG. **9** and FIG. **10**.

FIG. **9** is an equivalent circuit diagram of one pixel of a liquid crystal panel assembly according to another exemplary embodiment of the present invention.

Referring to FIG. **9**, like FIG. **3**, each pixel PX includes the first, second, and third subpixels PXa, PXb, and PXc, each subpixel PXa, PXb, and PXc includes the first, second, and third switching elements Qa, Qb, and Qc respectively connected to the corresponding gate line GL and the corresponding data line DL and the first, second, and third liquid crystal capacitors $Clca$, $Clcb$, and $Clcc$ connected thereto. The first

subpixel PXa includes the first switching element Qa and the first storage capacitor C_{sta} connected to the first storage electrode line SLa. The second subpixel PXb includes the second switching element Qb and the second and third storage capacitors C_{stm} and C_{stn} connected to the first and second storage electrode lines SLa and SLb, respectively.

However, different from FIG. **3**, the liquid crystal panel assembly of FIG. **9** includes the third subpixel PXc having the fourth storage capacitor C_{stc} connected to the third switching element Qc and the second storage electrode line SLb.

Next, the detailed structure of the liquid crystal panel assembly of FIG. **9** will be described with reference to FIG. **10**.

FIG. **10** is a layout view of a liquid crystal panel assembly according to another exemplary embodiment of the present invention.

Like the liquid crystal panel assembly of FIG. **4**, FIG. **5**, and FIG. **6**, a liquid crystal panel assembly of FIG. **10** includes a lower panel (not shown) and an upper panel (not shown) facing each other, a liquid crystal layer (not shown) disposed between the two panels, and a pair of polarizers (not shown) attached to the outside surfaces of the display panels.

The layered structure of the liquid crystal panel assembly according to the present exemplary embodiment is almost the same as the layered structure of the liquid crystal panel assembly shown in FIG. **5** and FIG. **6**.

In the lower panel, a plurality of gate lines **121** and a plurality of first and second storage electrode lines **131a** and **131b** are disposed on an insulation substrate (not shown). Each gate line **121** includes first, second, and third gate electrodes **124a**, **124b**, and **124c** and an end portion **129**. The storage electrode lines **131a** and **131b** include a plurality of storage electrodes **137a**, **137b**, **137c**, **137d**, **137e**, and **137f**. A gate insulating layer (not shown) is disposed on the gate lines **121** and the storage electrode lines **131a** and **131b**. A plurality of semiconductor islands **154a**, **154b**, and **154c** are disposed on the gate insulating layer, and a plurality of ohmic contact islands (not shown) are disposed thereon. A data conductor including a plurality of data lines **171** and a plurality of the first, second, and third drain electrodes **175a**, **175b**, and **175c** are disposed on the ohmic contacts. Each data line **171** includes a plurality of first, second, and third source electrodes **173a**, **173b**, and **173c** and an end portion **179**. A passivation layer (not shown) is disposed on the data conductors **171**, **175a**, **175b**, and **175c** and the exposed semiconductors **154a**, **154b**, and **154c**, and the passivation layer and the gate insulating layer have a plurality of contact holes **181**, **182**, **185a**, **185b**, and **185c** and a plurality of openings **187a**, **187b**, **187c**, **187d**, **187e**, and **187f**. A plurality of pixel electrodes **191** including the first, second, and third subpixel electrodes **191a**, **191b**, and **191c** and a plurality of contact assistants **81** and **82** are disposed on the passivation layer. An alignment layer (not shown) is disposed on the pixel electrode **191**, the contact assistants **81** and **82**, and the passivation layer.

In the upper panel, a light blocking member (not shown), a plurality of color filters (not shown), an overcoat (not shown), a common electrode (not shown), and an alignment layer (not shown) are disposed on an insulation substrate (not shown).

However, in the liquid crystal panel assembly according to the present exemplary embodiment, when comparing with the liquid crystal panel assembly shown in FIG. **4**, FIG. **5**, and FIG. **6**, the third storage electrode **137c** is connected to the second storage electrode line **131b**, not the first storage electrode line **131a**. Accordingly, the second storage electrode voltage V_{stb} is applied to the third storage electrode **137c**.

The first subpixel electrode **191a** overlaps with the first storage electrode line **131a**, which includes the first and second storage electrodes **137a** and **137b**.

The second subpixel electrode **191b** overlaps with the first storage electrode line **131a**, which includes the fourth storage electrode **137d**, and the second storage electrode line **131b**, which includes the sixth storage electrode **137f**. Here, the overlapping area between the second subpixel electrode **191b** and the first storage electrode line **131a** is substantially the same as the overlapping area between the second subpixel electrode **191b** and the second storage electrode line **131b**. The capacitance of the storage capacitor C_{stm} , which is formed by the first storage electrode line **131a** and the second subpixel electrode **191b**, may be the same as that of the storage capacitor C_{stn} , which is formed by the second storage electrode line **131** and the second subpixel electrode **191b**, in consideration of the overlapping area and the area of the openings **187d** and **187f**.

The third subpixel electrode **191c** is disposed below the first subpixel electrode **191a**, and overlaps with the second storage electrode line **131b**, which includes the third and fifth storage electrodes **137c** and **137e**.

Now, the driving of the liquid crystal display including the liquid crystal panel assembly shown in FIG. 9 and FIG. 10 will be described with reference to FIG. 11.

Referring to FIG. 11, the first, second, and third subpixel electrodes **191a**, **191b**, and **191c** that make up one pixel electrode **191** respectively receive the same data voltage V_d through the same data line DL at the same time through the respective switching elements Q_a , Q_b , and Q_c .

Accordingly, the voltage P_a , P_b , and P_c of each subpixel electrode **191a**, **191b**, and **191c** is increased by the same degree. Next, if the switching elements Q_a , Q_b , and Q_c are turned off, the first, second, and third subpixel electrodes **191a**, **191b**, and **191c** are floated. Here, the gate voltage V_g is changed from the gate-on voltage V_{on} to the gate-off voltage V_{off} such that each subpixel electrode voltage P_a , P_b , and P_c drops by the kick-back voltage V_{kb} . However, the first, second, and third subpixel electrodes **191a**, **191b**, and **191c** form the capacitors C_{sta} , C_{stb} , and C_{stc} along with the first and second storage electrode lines SL_a and SL_b such that the voltages of the first, second, and third subpixel electrodes **191a**, **191b**, and **191c** are changed according to the voltages of the first and second storage electrode lines SL_a and SL_b , then the voltages of the first, second, and third subpixel electrodes **191a**, **191b**, and **191c** are changed.

In detail, the voltage P_a of the first subpixel electrode is increased by the value ΔP_a according to the change of the first storage electrode signal V_{sta} .

The influences of the first storage electrode signal V_{sta} and the second storage electrode signal V_{stb} are offset such that the second subpixel electrode voltage P_b is maintained.

The third subpixel electrode **191c** is decreased by the value ΔP_c according to the change of the second storage electrode signal V_{stb} .

Accordingly, with reference to the common voltage V_{com} , the voltage of the first subpixel electrode **191a** becomes V_{pa1} , the voltage of the second subpixel electrode **191b** becomes V_{pb1} , and the voltage of the third subpixel electrode **191c** becomes V_{pc1} , and the order of the magnitude thereof is $V_{pa1} > V_{pb1} > V_{pc1}$. These subpixel electrode voltages V_{pa1} , V_{pb1} , and V_{pc1} are maintained during one frame.

Next, the polarity of the voltage applied to each subpixel electrode **191a**, **191b**, and **191c** is reversed in the next frame and the procedure of the previous frame is repeated, the voltage of the first subpixel electrode **191a** becomes V_{pa2} , the voltage of the second subpixel electrode **191b** becomes

V_{pb2} , and the voltage of the third subpixel electrode **191c** becomes V_{pc2} , and the order of the magnitude thereof is $V_{pa2} > V_{pb2} > V_{pc2}$.

Next, the effects of the liquid crystal displays according to the various exemplary embodiment of the present invention will be described with reference to FIG. 12A, FIG. 12B, FIG. 12C, and FIG. 12D.

FIG. 12A is a graph showing gamma curves of the front and the side of the liquid crystal display according to the conventional art, and FIG. 12B, FIG. 12C, and FIG. 12D are graphs showing gamma curves of the front and the side of the liquid crystal display according to various exemplary embodiments of the present invention.

FIG. 12A shows a case of the liquid crystal display including a pixel electrode that is divided into two subpixel electrodes that are spaced apart from each other, and FIG. 12B, FIG. 12C, and FIG. 12D show cases of the liquid crystal display including a pixel electrode that is divided into three subpixel electrodes that are spaced apart from each other. FIG. 12B shows the case in which the area ratio of the first, second, and third subpixel electrodes **191a**, **191b**, and **191c** is 1:2:1, the capacitance ratio of the first storage capacitor C_{sta} to the first liquid crystal capacitor Cl_{ca} is 1, and the capacitance ratio of the second storage capacitor C_{stb} to the second liquid crystal capacitor Cl_{cb} is 0.2 in the liquid crystal panel assembly of FIG. 3. FIG. 12C shows the case in which the area ratio of the first, second, and third subpixel electrodes **191a**, **191b**, and **191c** is 1.5:1.5:1, the capacitance ratio of the first storage capacitor C_{sta} to the first liquid crystal capacitor Cl_{ca} is 0.65, and the capacitance ratio of the third storage capacitor C_{stc} to the third liquid crystal capacitor Cl_{cc} is 0.65 in the liquid crystal panel assembly of FIG. 9. FIG. 12D shows the case in which the area ratio of the first, second, and third subpixel electrodes **191a**, **191b**, and **191c** is 1:2:1, the capacitance ratio of the first storage capacitor C_{sta} to the first liquid crystal capacitor Cl_{ca} is 0.8, and the capacitance ratio of the third storage capacitor C_{stc} to the third liquid crystal capacitor Cl_{cc} is 0.65 in the liquid crystal panel assembly of FIG. 9.

The index of visibility is 0.250 in the case of FIG. 12A, which may be better than the index of visibility of the general case in which the pixel electrode is not divided. Here, the index of visibility is the index in which the distortion amount of the side gamma for the front gamma is quantified. However, a turning point at which the gamma curve is rapidly changed is generated in portion A of the side gamma curve, and the curved line is swollen in portion B. Like this, when the side gamma curve is not smoothly changed, the change of the color or the luminance is not natural in the side of the liquid crystal display and the phenomenon in which the color or the luminance is rapidly changed is generated such that the screen is unpleasantly shown.

This phenomenon is generated since the corresponding liquid crystal molecules are suddenly moved, when the subpixel having a relatively low voltage among two subpixels starts to contribute to the entire voltage over the some gray.

On the other hand, the indexes of visibility were respectively 0.224, 0.204, and 0.204 in the cases of FIG. 12B, FIG. 12C, and FIG. 12D. Also, the generation of the phenomena of a turning point and swelling may be prevented in the side gamma curve in the respective cases, and the side gamma curve may be comparably smooth. In the liquid crystal display according to the present invention, the entire pixel is divided into three subpixels having different voltages from each other such that the subpixel having the relatively low voltage may be divided into two. Accordingly, when the subpixel having the relatively low voltage among two subpixels

starts to contribute to the entire voltage over the some gray, even though the corresponding liquid crystal molecules may suddenly move, because the corresponding portion is divided in two, the influence may be reduced such that the side gamma curve may be smooth.

Accordingly, to prevent the phenomena of a turning point and swelling of the side gamma curve and to obtain a sufficient index of visibility, in relation to the common voltage V_{com} , the first subpixel electrode voltage V_{pa1} may be higher than the third subpixel electrode voltage V_{pc1} by 0.5 V to 1.5 V, and the second subpixel electrode voltage V_{pb1} may be higher than the third subpixel electrode voltage V_{pc1} by 0.1 V to 1.0 V in the case of the liquid crystal display of FIG. 3. In the case of the liquid crystal display of FIG. 9, in relation to the common voltage V_{com} , the first subpixel electrode voltage V_{pa1} is higher than the second subpixel electrode voltage V_{pb1} by 0.5 V to 1.5 V, and the third subpixel electrode voltage V_{pc1} is less than the second subpixel electrode voltage V_{pb1} by 0.5 V to 1.5 V.

According to exemplary embodiments of the present invention, the improved index of visibility may be maintained and the screen deterioration generated at the side of the liquid crystal display may be minimized, as compared with the case in which the pixel electrode is divided into two.

It will be apparent to those skilled in the art that various modifications and variation can be made in the present invention without departing from the spirit or scope of the invention. Thus, it is intended that the present invention cover the modifications and variations of this invention provided they come within the scope of the appended claims and their equivalents.

What is claimed is:

1. A display panel, comprising:

a pixel electrode comprising a first subpixel electrode, a second subpixel electrode, and a third subpixel electrode insulated from each other;

a first thin film transistor connected to the first subpixel electrode;

a second thin film transistor connected to the second subpixel electrode;

a third thin film transistor connected to the third subpixel electrode;

a gate line connected to the first thin film transistor, the second thin film transistor, and the third thin film transistor;

a data line connected to the first thin film transistor, the second thin film transistor, and the third thin film transistor; and

a voltage differentiating member to change respective voltages of the first subpixel electrode, the second subpixel electrode, and the third subpixel electrode to be different from each other.

2. The display panel of claim 1, wherein:

the first thin film transistor, the second thin film transistor, and the third thin film transistor each include a gate electrode, a source electrode, and a drain electrode;

the gate electrodes of the first thin film transistor, the second thin film transistor, and the third thin film transistor are connected to the gate line;

the source electrodes of the first thin film transistor, the second thin film transistor, and the third thin film transistor are connected to the data line; and

the drain electrodes of the first thin film transistor, the second thin film transistor, and the third thin film transistor are spaced apart from each other.

3. The display panel of claim 2, wherein

a voltage of the first subpixel electrode (“first subpixel voltage”) is higher than a voltage of the second subpixel electrode (“second subpixel voltage”), and the second subpixel voltage is higher than a voltage of the third subpixel electrode (“third subpixel voltage”).

4. The display panel of claim 3, wherein

the first subpixel voltage is higher than the third subpixel voltage by 0.5 V to 1.5 V, and the second subpixel voltage is higher than the third subpixel voltage by 0.1 V to 1.0 V.

5. The display panel of claim 3, wherein:

the first subpixel voltage is higher than the second subpixel voltage by 0.5 V to 1.5 V, and the third subpixel voltage is less than the second subpixel voltage by 0.5 V to 1.5 V.

6. The display panel of claim 3, wherein the voltage differentiating member comprises:

a first storage electrode line overlapping with the first subpixel electrode, the second subpixel electrode, and the third subpixel electrode;

a second storage electrode line overlapping with the second subpixel electrode and the third subpixel electrode, and wherein the first storage electrode line and the second storage electrode line respectively receive a first storage voltage and a second storage voltage having opposite phases from each other.

7. The display panel of claim 6, wherein

an overlapping area between the second subpixel electrode and the first storage electrode line is larger than an overlapping area between the second subpixel electrode and the second storage electrode line, and an overlapping area between the third subpixel electrode and the first storage electrode line and an overlapping area between the third subpixel electrode and the second storage electrode line are the same.

8. The display panel of claim 3, wherein the voltage differentiating member comprises:

a first storage electrode line overlapping with the first subpixel electrode and the second subpixel electrode; and a second storage electrode line overlapping with the second subpixel electrode and the third subpixel electrode, and wherein the first storage electrode line and the second storage electrode line respectively receive a first storage voltage and a second storage voltage having opposite phases from each other.

9. The display panel of claim 8, wherein

an overlapping area between the second subpixel electrode and the first storage electrode line and an overlapping area between the second subpixel electrode and the second storage electrode line are the same.

10. The display panel of claim 3, wherein an area of the first subpixel electrode is in the range of 10% to 50% of the entire area of the pixel electrode.

11. The display panel of claim 3, wherein an area of the second subpixel electrode is in the range of 20% to 50% of the entire area of the pixel electrode.

12. The display panel of claim 3, wherein an area of the third subpixel electrode is in the range of 40% to 70% of the entire area of the pixel electrode.

13. The display panel of claim 2, wherein

each gate electrode of the first thin film transistor, the second thin film transistor, and the third thin film transistor are connected to each other, and each source electrode of the first thin film transistor, the second thin film transistor, and the third thin film transistor are connected to each other.

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14. The display panel of claim 1, wherein:
an area ratio of the first subpixel electrode, the second
subpixel electrode, and the third subpixel electrode is
1:2:1.

15. The display panel of claim 1, wherein:
an area ratio of the first subpixel electrode, the second
subpixel electrode, and the third subpixel electrode is
1.5:1.5:1.

16. The display panel of claim 1, wherein the voltage
differentiating member is coupled to each of the first subpixel
electrode, the second subpixel electrode, and the third sub-
pixel electrode to change the respective voltages to be differ-
ent from each other.

17. A liquid crystal display, comprising:

a gate line;

a data line crossing the gate line;

a first storage electrode line and a second storage electrode
line; and

a pixel connected to the gate line and the data line,
wherein the pixel comprises:

a first liquid crystal capacitor comprising a first subpixel
electrode,

a second liquid crystal capacitor comprising a second sub-
pixel electrode,

a third liquid crystal capacitor comprising a third subpixel
electrode,

a first storage capacitor coupled in parallel to the first liquid
crystal capacitor and connected to the first storage elec-
trode line,

a second storage capacitor coupled in parallel to the second
liquid crystal capacitor and connected to the first storage
electrode line and the second storage electrode line, and
a third storage capacitor coupled in parallel to the third
liquid crystal capacitor and connected to the first storage
electrode line and the second storage electrode line,

wherein the first storage electrode line and the second
storage electrode line receive storage electrode signals
having opposite phases from each other, and

wherein charging voltages of the first liquid crystal capaci-
tor, the second liquid crystal capacitor, and the third
liquid crystal capacitor are different from each other.

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18. The liquid crystal display of claim 17, wherein
the charging voltage of the first liquid crystal capacitor is
higher than the charging voltage of the third liquid crys-
tal capacitor by 0.5 V to 1.5 V, and the charging voltage
of the second liquid crystal capacitor is higher than the
charging voltage of the third liquid crystal capacitor by
0.1 V to 1.0 V.

19. A liquid crystal display, comprising:

a gate line;

a data line crossing the gate line;

a first storage electrode line and a second storage electrode
line; and

a pixel connected to the gate line and the data line,
wherein the pixel comprises:

a first liquid crystal capacitor comprising a first subpixel
electrode,

a second liquid crystal capacitor comprising a second sub-
pixel electrode,

a third liquid crystal capacitor comprising a third subpixel
electrode,

a first storage capacitor coupled in parallel to the first liquid
crystal capacitor and connected to the first storage elec-
trode line,

a second storage capacitor coupled in parallel to the second
liquid crystal capacitor and connected to the first storage
electrode line and the second storage electrode line, and
a third storage capacitor coupled in parallel to the third
liquid crystal capacitor and connected to the second
storage electrode line,

wherein the first storage electrode line and the second
storage electrode line receive storage electrode signals
having opposite phases from each other, and

wherein the charging voltages of the first liquid crystal
capacitor, the second liquid crystal capacitor, and the
third liquid crystal capacitor are different from each
other.

20. The liquid crystal display of claim 19, wherein
the charging voltage of the first liquid crystal capacitor is
higher than the charging voltage of the second liquid
crystal capacitor by 0.5 V to 1.5 V, and the charging
voltage of the third liquid crystal capacitor is less than
the charging voltage of the second liquid crystal capaci-
tor by 0.5 V to 1.5 V.

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专利名称(译)	显示面板和包括其的液晶显示器		
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摘要(译)

显示面板和包括该显示面板的液晶显示器技术领域显示面板包括像素电极，其包括彼此绝缘的第一子像素电极，第二子像素电极和第三子像素电极，连接到第一子像素电极的第一薄膜晶体管，连接到第一子像素电极的第二薄膜晶体管。第二子像素电极，连接到第三子像素电极的第三薄膜晶体管，连接到第一，第二和第三薄膜晶体管的栅极线，连接到第一，第二和第三薄膜晶体管的数据线，以及电压微分构件改变第一，第二和第三子像素电极的电压，第一，第二和第三子像素电极的电压彼此不同。

